G.R. No.

Paper Code - UTI7-104 A (T2)

SEPTEMBER 2017 / IN - SEM (T2)

F. Y. B.TECH. (COMMON) (SEMESTER - I)

COURSE NAME: Basic Electronics Engineering

(2017 PATTERN)

Time : [1 Hour]

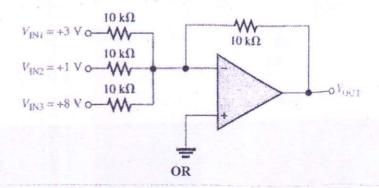
[Max. Marks: 30]

(*) Instructions to candidates:

- 1) Answer Q.1 OR Q.2, Q.3 OR Q.4
- 2) Figures to the right indicate full marks.
- 3) Use of scientific calculator is allowed
- 4) Use suitable data where ever required
- Q1 a) Draw and explain the operation of N channel Enhancement-MOSFET [6] with its characteristics.
 - b) Draw and Explain working of SCR with V-I characteristics. [6]
 - c) For N-channel Enhancement -MOSFET ID_(on) =500mA at VGS=10V [4] and Vth=1V. Find ID when VGS=5V.

OR

- Q2 a) Draw and Explain working of TRIAC with V-I characteristics.
 - Explain controlled full wave rectifier using SCR with neat diagram and waveforms
 - c) Compare features of BJT and MOSFET. Draw symbols of P-Channel [4] and N-Channel Enhancement type MOSFET.
- Q3 a) Draw the circuit of close loop inverting amplifier. Derive the expression [6] for gain of inverting amplifier. Draw input & output waveforms.
 - b) Draw the block diagram of Op-Amp. Label the blocks. State the function [4] of each block.
 - c) Determine the output voltage in following Figure: [4]



Q4	a)	Draw the circuit of close loop non inverting amplifier. Derive the expression for gain of non inverting amplifier. Draw input & output waveforms.	[6]
	b)	Explain following parameters of op-amp a) Slew rate	[4]
	c)	b) Input offset current & Input bias current. A certain op-amp has an differential voltage gain of 100,000 and a Common-mode gain of 0.2. Determine the CMRR and express it in decibels.	[4]